Single P-channel MOSFET

KFJ9B0458ZL **Datasheet**

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1. GENERAL DESCRIPTION

Single P-channel MOSFET for automotive.

2. FEATURES

- Drain-source On-state Resistance: RDS(on) typ = $10 \text{ m}\Omega$ (VGS = 10 V)
- · CSP (Chip Size Package)
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL: Level 1)
- · AEC-Q101 Qualified

3. MARKING SYMBOL: WV

4. PACKAGING

Embossed type (Thermo-compression sealing): 8,000 pcs / reel (standard)

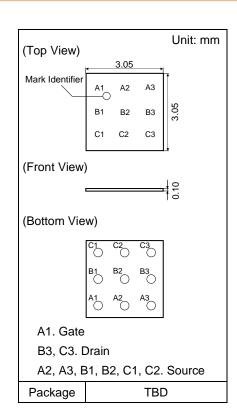
5. ABSOLUTE MAXIMUM RATINGS Ta = 25 °C

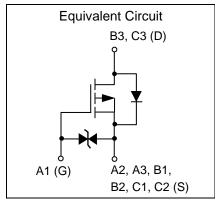
Parameter		Symbol	Rating	Unit	
Drain-source Voltage		VDS	- 40	V	
Gate-source Voltage		VGS	- 20 / + 10	V	
	DC *1	ID1	- 8.1	А	
Drain Current	DC *2	ID2	- 11.6		
Drain Current	DC *3	ID3	- 13.8		
	Pulsed*4	IDp	- 92.8		
	DC *1	PD1	0.86		
Total Power Dissipation	DC *2	PD2	1.75	W	
	DC *3	PD3	2.50		
Operating Junction and Storage Temperature Range		Tj, Tstg	- 55 to + 150	°C	

6. THERMAL CHARACTERISTICS Ta = 25 °C

Parameter	Symbol	Rating	Unit
	Rth1 *1	145	
Thermal Resistance (ch-a)	Rth2 *2	72	°C / W
	Rth3 *3	50	

- Note *1 Mounted on FR4 board (25.4 mm x 25.4 mm x t1.0 mm). FR4 board partially covered with copper pad (79.9 mm² area, 36 µm thickness).
 - *2 Mounted on FR4 board (25.4 mm x 25.4 mm x t1.0 mm). FR4 board fully covered with copper pad (616 mm² area, 36 µm thickness).
 - *3 Mounted on ceramic board (70 mm x 70 mm x t1.0 mm).
 - *4 $t = 10 \mu s$, Duty Cycle $\leq 1 \%$.





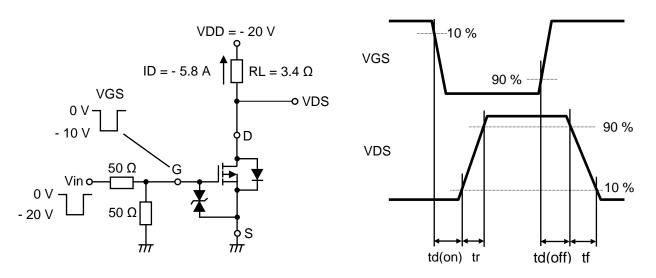
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7. ELECTRICAL CHARACTERISTICS Ta = 25 °C ± 3 °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit	
Drain-source Breakdown Voltage	VDSS	ID = - 1 mA, VGS = 0 V	- 40			V	
Zero Gate Voltage Drain Current	IDSS	VDS = - 40 V, VGS = 0 V			- 1	μΑ	
Cata aguiras Laglagas Current	IGSS	VGS = - 16 V, VDS = 0 V			- 10		
Gate-source Leakage Current		VGS = + 8 V, VDS = 0 V			10	μA	
Gate-source Threshold Voltage	Vth	ID = - 28.6 mA, VDS = - 10 V	- 1	- 2	- 3	V	
Drain aguras On state Posistanes	RDS(on)1	ID = - 2 A, VGS = - 10 V	6	10	13	mΩ	
Drain-source On-state Resistance	RDS(on)2	ID = - 2 A, VGS = - 4.5 V	7	12	20		
Body Diode Forward Voltage	VF(s-d)	IF = - 2 A, VGS = 0 V		- 0.8	- 1.0	V	
Input Capacitance *1	Ciss	VDC 20 V VCC 0 V		7500		pF	
Output Capacitance *1	Coss	VDS = - 20 V, VGS = 0 V f = 1 MHz		500			
Reverse Transfer Capacitance *1	Crss			450			
Turn-on Delay Time *1, *2	td(on)	VDD = - 20 V, VGS = 0 to - 10 V		40			
Rise Time *1, *2	tr	ID = - 5.8 A		70			
Turn-off Delay Time *1, *2	td(off)	VDD = - 20 V, VGS = - 10 to 0 V		580		ns	
Fall Time *1, *2	tf	ID = - 5.8 A		200			
Total Cata Charres *1	Qg1	VDD = - 20 V, VGS = - 4.5 V		70			
Total Gate Charge *1	Og2	ID = - 11.6 A		140		nC	
Gata course Charge *1	Qg2	VDD = - 20 V, VGS = - 10 V		20		110	
Gate-source Charge *1	Qgs	ID = - 11.6 A		1		-	
Gate-drain Charge *1	Qgd			26			

Note Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

- *1 Guaranteed by design, not subject to production testing.
- *2 Measurement circuit for Turn-on Delay Time / Rise Time / Turn-off Delay Time / Fall Time.

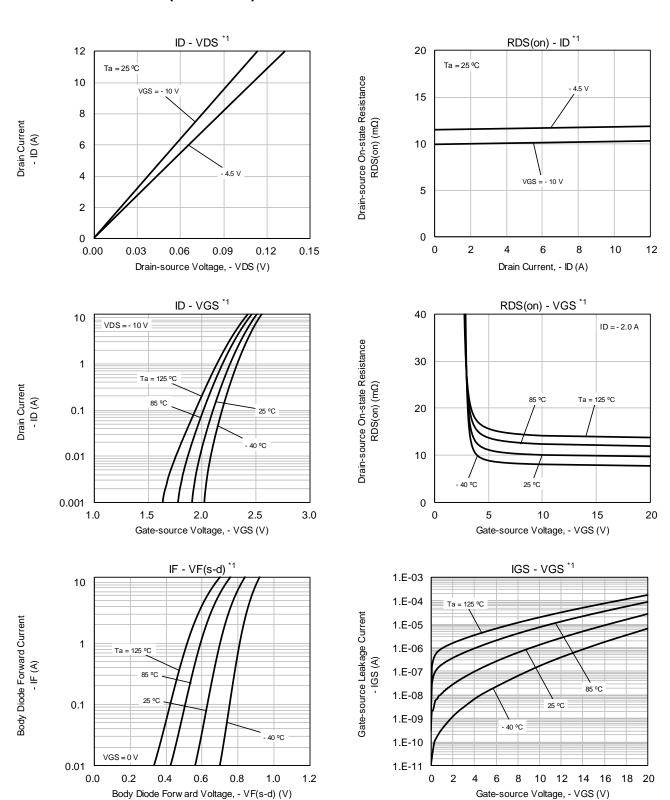


8. ELECTROSTATIC DISCHARGE CHARACTERISTIC $Ta = 25 °C \pm 3 °C$

Standard	Test Type	Symbol	Conditions	Class	Value	Unit
AEC-Q101-001	Human Body Model	HBM	$C = 100 \text{ pF}, R = 1.5 \text{ k}\Omega$	НЗА	> 4 to ≤ 8	kV



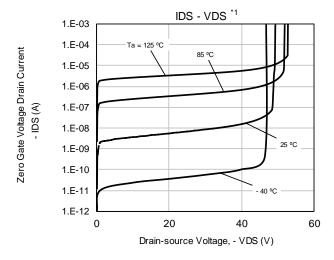
9. TECHNICAL DATA (Reference)

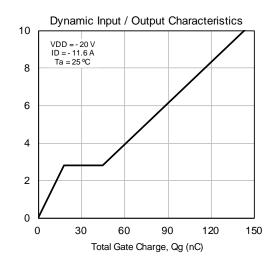


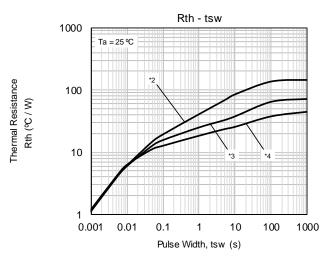
Gate-source Voltage

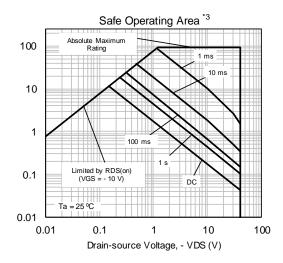
Drain Current - ID (A)

TECHNICAL DATA (Reference)









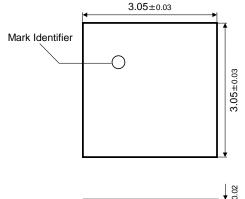
Note

- *1 Pulse measurement.
- *2 Mounted on FR4 board (25.4 mm x 25.4 mm x t1.0 mm). FR4 board partially covered with copper pad ($79.9~\text{mm}^2$ area, $36~\mu\text{m}$ thickness).
- *3 Mounted on FR4 board (25.4 mm x 25.4 mm x t1.0 mm). FR4 board fully covered with copper pad (616 mm² area, 36 μm thickness).
- *4 Mounted on ceramic board (70 mm x 70 mm x t1.0 mm).

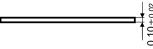
10. OUTLINE

(Top View)

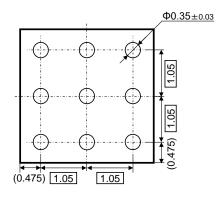
Unit: mm



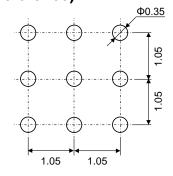
(Front View)



(Bottom View)



11. LAND & STENCIL PATTERN (Reference)



Unit: mm

Important notice:

Solder Mask Defined (SMD) pattern is strongly recommended for pad design.

Please check the information in the Nuvoton WL-CSP Application Notes about mounting process.

ADVANCE INFORMATION



KFJ9B0458ZL

12. REVISION HISTORY

Date	Revision	Description	
2021.11.19	1.00	1. Initially issued.	

(FJ9B0458ZL DATASHEET)



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